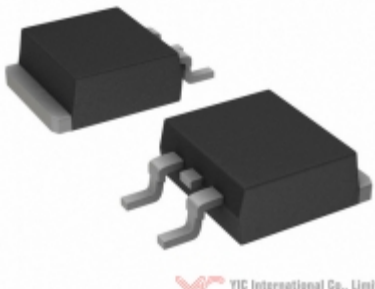
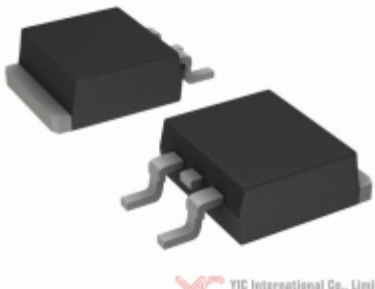

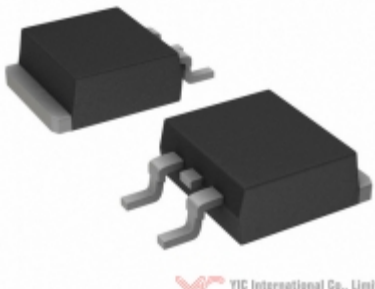
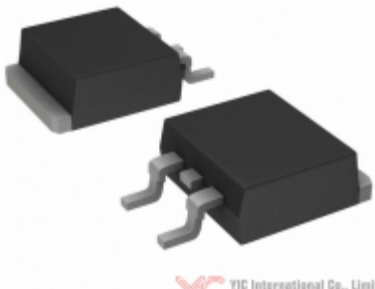
	<b>FQB5P10TM</b>	
	<b>Hersteller-Teilenummer:</b>	FQB5P10TM
	<b>Hersteller / Marke:</b>	AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b>	MOSFET P-CH 100V 4.5A D2PAK
	<b>Datenblätter:</b>	 <a href="#">FQB5P10TM.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 5000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
	Image may be representation. See specs for product details.	

### Spezifikationen

Teilenummer	FQB5P10TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 100V 4.5A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	5000 pcs Stock
detaillierte Beschreibung	P-Channel 100V 4.5A (Tc) 3.75W (Ta), 40W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 40W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	1.05 Ohm @ 2.25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	250pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQB5P10TM ist neu im Original, Suche FQB5P10TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB5P10TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB5P10TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB5P20TMX</b> Fairchild/ON Semiconductor FQB5P20TMX FAIRCHILD</p>	 <p><b>FQB5P10TM</b> Fairchild/ON Semiconductor MOSFET P-CH 100V 4.5A D2PAK</p>	 <p><b>FQB5N90</b> FAIRCHILD FQB5N90 FAIRCHILD</p>	 <p><b>FQB60N03L</b> FSC FSC TO-263</p>
 <p><b>FQB5P10</b> F FQB5P10 F</p>	 <p><b>FQB6035AL</b> FSC FSC TO-263</p>	 <p><b>FQB5P20TM</b> Fairchild/ON Semiconductor MOSFET P-CH 200V 4.8A D2PAK</p>	 <p><b>FQB5N90TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 5.4A D2PAK</p>

heiße Teile

Mehr

 FQB50N06	 FQB50N06C	 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM
 FQB50N06M	 FQB50N06TM	 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM
 FQB55N06TM	 FQB55N10	 FQB55N10TM	 FQB55N10TM	 FQB5N20L
 FQB5N30TM	 FQB5N30TM	 FQB5N50C	 FQB5N50CF	 FQB5N50CTM
 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM	 FQB5N90TM	 FQB5N90TM
 FQB5P10TM	 FQB630TM	 FQB630TM	 FQB65N06	 FQB65N06TM
 FQB65N06TM	 FQB6N40C	 FQB6N40CF	 FQB6N40CTM	 FQB6N40CTM
 FQB6N50TM	 FQB6N50TM	 FQB6N60C	 FQB6N60CTM	 FQB6N60CTM
 FQB6N60TM	 FQB6N60TM	 FQB6N70TM	 FQB6N70TM	 FQB6N90TM
 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB	 FQB7045FB	 FQB70N03

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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